# NSN 5961-01-612-5657

Semiconductor Device Rectifier - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-612-5657

Overall	Lenath:
Overan	LCHAHI.

Between 2.120 inches and 2.200 inches

**Overall Diameter:** 

Between 0.06 inches and 0.09 inches

#### **Operating Tempurature Range:**

-65.0 to 175.0 degrees celsius

### **End Application:**

Ah-1 4 bladed rotor head upgrade, wiring integ assembly, wiring board assembly

#### **Absolute Maximum Voltage Rating In Volts Per Characteristic:**

225.0 reverse voltage, average and 275.0 breakdown voltage, instantaneous

**Product Name:** 

Silicon rectifier diodes

#### **Special Features:**

Description: 600mw power dissipation, 400ma avg. Forward rectified current, body length: 0.120-.200", lead dia. 0.018-.022", lead length:

1.0"

Material:

Glass

#### **Terminal Type And Quantity:**

2 wire lead

**Shelf Life:** 

N/a

**Unit Of Measure:** 

--

## Demilitarization:

Yes - demil/mli

Fiig:

A503h0